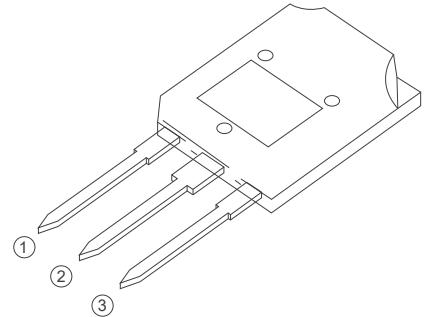


IT(RMS)		80A
VDRM/VRRM		1200V
VTM		1.8V

FEATURES

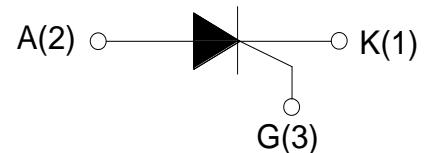
IT(RMS): 80A
 VGT: 1.5V
 VDRM VRRM:1200V
 High Junction Temperature
 Good Commutation Performance



TO-247S

APPLICATIONS

Heater Control
 Motor Speed Controller
 Washing machine
 Vacuums
 Solid state relay

**Absolute Maximum Ratings** ($T_j=25^\circ\text{C}$ unless otherwise specified)

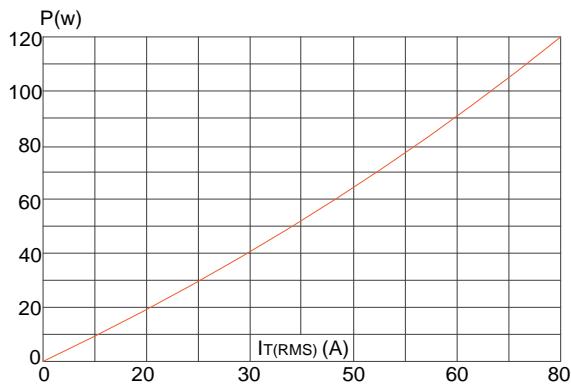
Symbol	Parameter	Conditions	Ratings	Unit
VDRM VRRM	Repetitive Peak Off-State Voltage	TYN8012	1200	V
		TYN8016	1600	V
IT(RMS)	R.M.S On-State Current		80	A
ITSM	Surge On-State Current	$f=50\text{Hz}, t_p=10\text{ms}/8.3\text{ms}$	800	A
I^2t	I^2t for fusing	$t_p=10\text{ms}$	7800	A^2s
PG(AV)	Average Gate Power Dissipation	$T_j=125^\circ\text{C}$	1	W
PGM	Peak Gate Current	$T_j=125^\circ\text{C}$	5	W
IGM	Peak Gate Current	$t_p=10\mu\text{s}$	4	A
T_j	Operating Junction Temperature		$\sim 40 \sim 125$	$^\circ\text{C}$
TSTG	Storage Temperature		$\sim 40 \sim 150$	$^\circ\text{C}$

Electrical Characteristics ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Value	Unit
IDRM	Repetitive Peak Off-State Current	$T_c=25^\circ\text{C}$	≤ 50	uA
		$T_c=125^\circ\text{C}$	≤ 10	mA
IRRM	Repetitive Peak Reverse Current	$T_c=25^\circ\text{C}$	≤ 50	uA
		$T_c=125^\circ\text{C}$	≤ 10	mA
VTM	Forward "on" voltage	$I_T=100\text{A}$ $t_p=380\text{us}$	≤ 1.8	V
VGD	Gate nontrigger voltage	$V_D=V_{DRM}, T_j=125^\circ\text{C}$, $R_L=3.3\text{K}\Omega$	≥ 0.25	V
IL	Latching current	$I_G=1.2I_{GT}$	≤ 200	mA
IH	Holding current	$V_D=12\text{V}$, $I_{GT}=0.1\text{A}$	≤ 150	mA
VGT	Gate trigger voltage	$V_D=12\text{V}$	≤ 1.5	V
IGT	Gate trigger current	$V_D=12\text{V}, I_T=0.1\text{A}$	≤ 80	mA
dv/dt	Critical-rate of rise of commutation voltage	$V_D=2/3V_{DRM}, T_j=125^\circ\text{C}$, gate open circuit	≥ 1000	V/us
di/dt	Critical-rate of rise of commutation current	$I_G=2XIG, tr=100\text{us}, T_j=125^\circ\text{C}$	≥ 150	A/us
Rth(j-c)	Thermal resistance	Junction to case	0.43	°C/W

FIG1

Maximum power dissipation versus RMS on-state current

**FIG2**

RMS on-state current versus case temperature

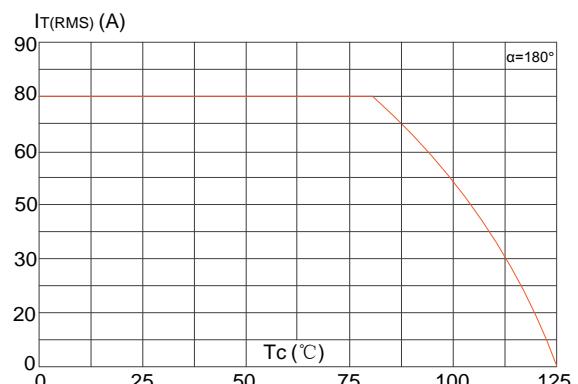
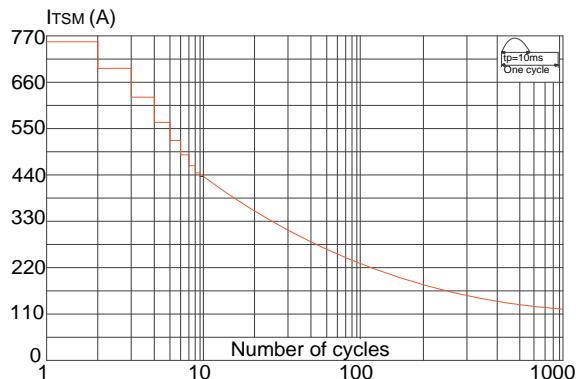
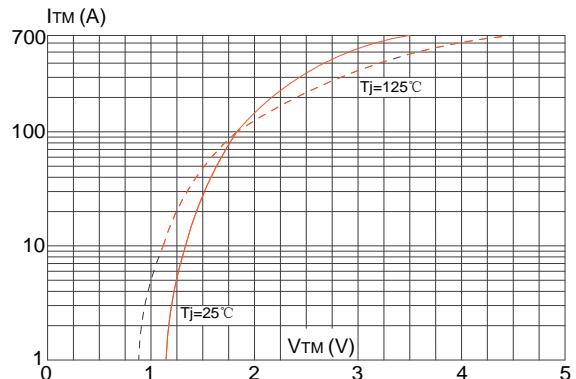


FIG3

Surge peak on-state current versus number of cycles


FIG4

On-state characteristics (maximum values)


FIG5

Non-repetitive surge peak on-state current for a sinusoidal pulse with width $tp < 20ms$, and corresponding value of I^2t ($dl/dt < 100A/\mu s$)

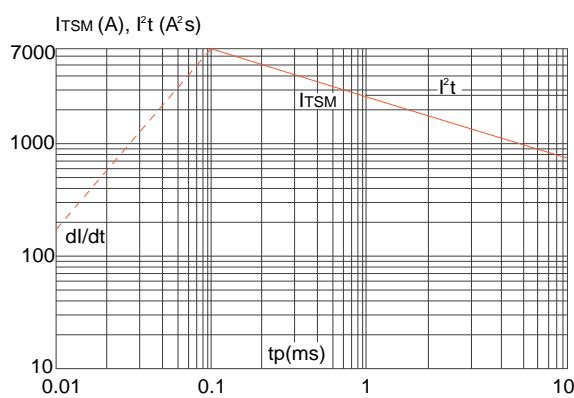
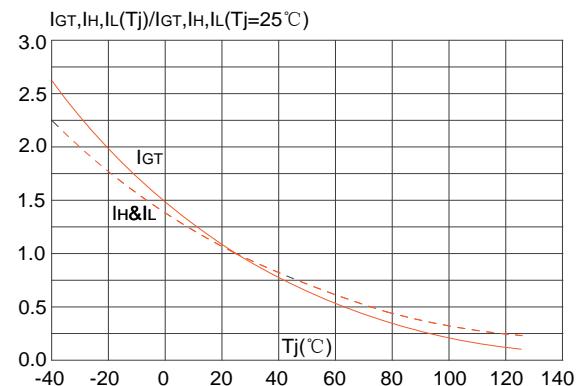
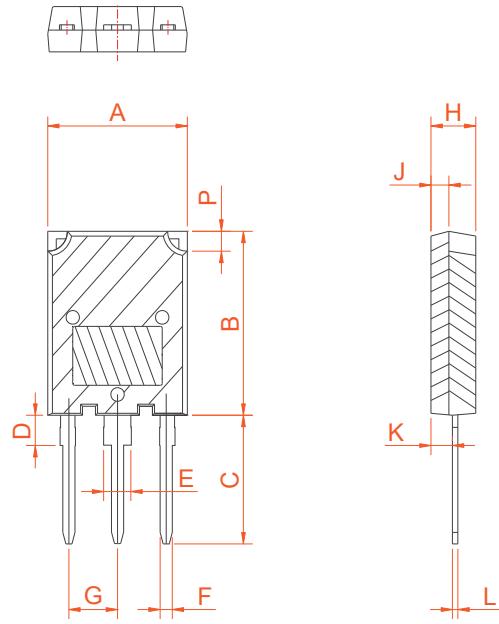

FIG6

FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.1		16.1	0.594		0.634
B	19.8		20.8	0.78		0.819
C	13.8		14.8	0.543		0.583
D	3.00		4.00	0.118		0.157
E	2.75		3.35	0.108		0.132
F	1.30		1.50	0.051		0.059
G	5.10		5.80	0.201		0.228
H	4.50		5.50	0.177		0.217
J	1.45		2.15	0.057		0.085
K	1.90		2.80	0.075		0.110
L	0.55		0.80	0.022		0.031
P	2.00		2.40	0.079		0.094

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